Transmitter 32.0-45.0 GHz



- Sub-harmonic Transmitter
- Integrated Mixer, LO Doubler/Buffer & Output Amplifier
- +14.0 dBm Output Third Order Intercept (OIP3)
- +4.0 dBm LO Drive Level
- 5.0 dB Conversion Gain
- 100% On-Wafer RF and DC Testing
- 100% Commercial-Level Visual Inspection Using Mil-Std-883 Method 2010
- RoHS* Compliant and 260°C Reflow Compatible

Description

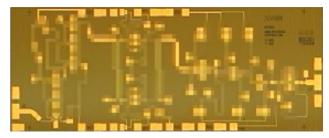
M/A-COM Tech's 32.0-45.0 GHz GaAs MMIC transmitter has a +14.0 dBm output third order intercept across the band. This device is a balanced, resistive pHEMT mixer followed by a distributed output amplifier and includes an integrated LO doubler and LO buffer amplifier. The use of integrated LO doubler and LO buffer amplifier makes the provision of the LO easier than for fundamental mixers at these frequencies. IF and IF mixer inputs are provided and an external 180 degree hybrid is required to select the desired sideband. This MMIC uses M/A-COM Tech's GaAs PHEMT device model technology, and is based upon electron beam lithography to ensure high repeatability and uniformity. The chip has surface passivation to protect and provide a rugged part with backside via holes and gold metallization to allow either a conductive epoxy or eutectic solder die attach process. This device is well suited for Millimeterwave Point-to-Point Radio, LMDS, SATCOM and VSAT applications.

Ordering Information

1

Part Number	Package
XU1004-BD-000V	Where "V" is RoHS compli- ant die packed in vacuum released gel paks
XU1004-BD-EV1	evaluation module

Chip Device Layout



Absolute Maximum Ratings

Parameter	Absolute Max.
Supply Voltage (Vd)	+6.0 VDC
Supply Current (Id1,2)	200,180 mA
Gate Bias Voltage (Vg)	+0.3 VDC
Input Power (IF Pin)	0.0 dBm
Storage Temperature (Tstg)	-65 °C to +165 °C
Operating Temperature (Ta)	-55 °C to Table ¹
Channel Temperature (Tch)	MTTF Table ¹

(1) Channel temperature affects a device's MTTF. It is recommended to keep channel temperature as low as possible for maximum life.

- North America Tel: 800.366.2266
 Europe Tel: +353.21.244.6400
 India Tel: +91.80.43537383
 China Tel: +86.21.2407.1588
- Visit www.macomtech.com for additional data sheets and product information.

is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. **PRELIMINARY:** Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions



Rev. V1

Mimix Broadband

M/A-COM Technology Solutions Inc. and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice.



Transmitter 32.0-45.0 GHz

Rev. V1 Mimix Broadband

Electrical Specifications: 35-45 GHz (RF/Upper Side Band) (Ambient Temperature T=25°C)

Parameter	Units	Min.	Тур.	Max.
Frequency Range (RF) Lower Side Band	GHz	32.0	-	42.0
Frequency Range (LO)	GHz	16.0	-	25.0
Frequency Range (IF)	GHz	DC	-	4.0
Input Return Loss RF (S22)	dB	-	10.0	-
Small Signal Conversion Gain RF/IF (S21) ²	dB	-	5.0	-
LO Input Drive (P _{LO})	dBm	-	+4.0	-
Isolation LO/RF @ LOx1	dB	-	TBD	-
Isolation LO/RF @ LOx2	dB	-	TBD	-
Output Third Order Intercept (OIP3) ^{1,2}	dBm	-	+14.0	-
Drain Bias Voltage (Vd1,2)	VDC	-	+4.0	+5.5
Gate Bias Voltage (Vg1,2)	VDC	-1.2	-0.3	+0.1
Gate Bias Voltage (Vg3,4) Mixer, Doubler	VDC	-1.2	-0.5	+0.1
Supply Current (Id1) (Vd1=4.0 V, Vg=-0.3 V Typical)	mA	-	160	180
Supply Current (Id2) (Vd2=4.0 V, Vg=-0.3 V Typical)	mA	-	145	165

(1) Measured using constant current.

(2) Measured using LO Input drive level of 0.0.

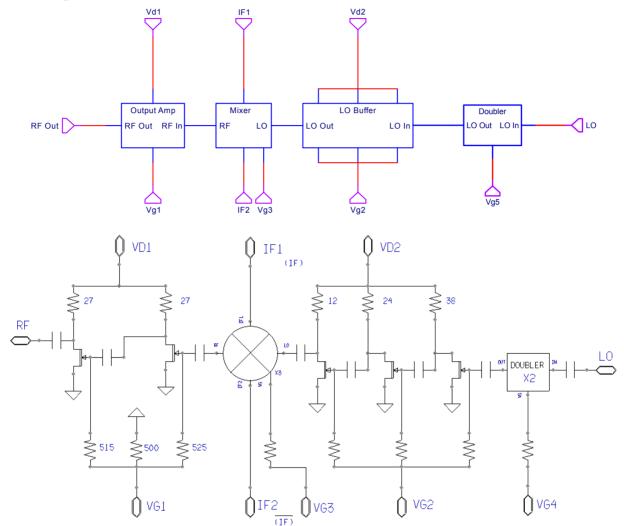
changes to the product(s) or information contained herein without notice.

Transmitter 32.0-45.0 GHz



Rev. V1 Mimi× Broadband

Block Diagram & Schematics



3

ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed. North America Tel: 800.366.2266
 Europe Tel: +353.21.244.6400
 India Tel: +91.80.43537383
 China Tel: +86.21.2407.1588

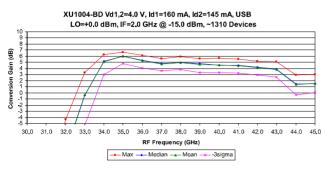
Visit www.macomtech.com for additional data sheets and product information.

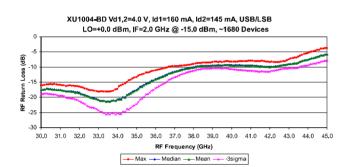


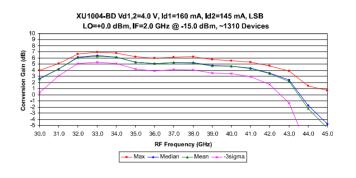
Transmitter 32.0-45.0 GHz

Rev. V1 Mimix Broadband

Typical Performance Curves



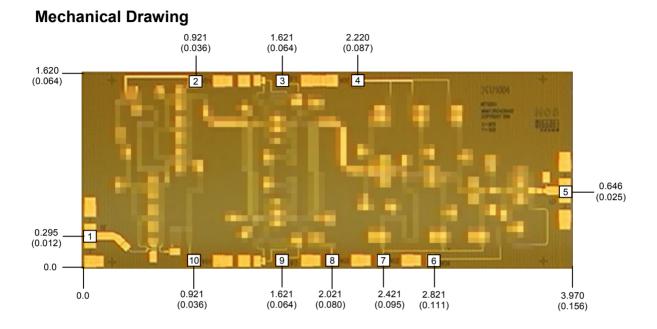




ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. **PRELIMINARY:** Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

Visit www.macomtech.com for additional data sheets and product information.

Transmitter 32.0-45.0 GHz



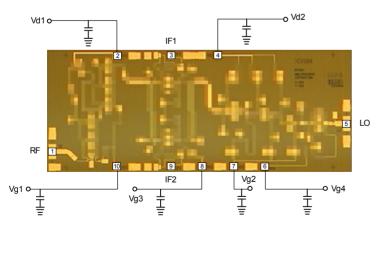
(Note: Engineering designator is 40TX0531)

Units: millimeters (inches) Bond pad dimensions are shown to center of bond pad. Thickness: 0.110 +/- 0.013 (0.0043 +/- 0.0004), Backside is ground, Bond Pad/Backside Metallization: Gold All DC/IF Bond Pads are 0.100 x 0.100 (0.004 x 0.004). All RF Bond Pads are 0.100 x 0.200 (0.004 x 0.008) Bond pad centers are approximately 0.109 (0.004) from the edge of the chip. Dicing tolerance: +/- 0.005 (+/- 0.0002). Approximate weight: 3.987 mg.

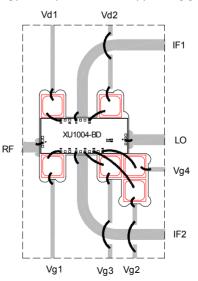
Bond Pad #1 (RF Out)	Bond Pad #3 (IF1)	Bond Pad #5 (LO)	Bond Pad #7 (Vg2)	Bond Pad #7 (IF2)
Bond Pad #2 (Vd1)	Bond Pad #4 (Vd2)	Bond Pad #6 (Vg4)	Bond Pad #8 (Vg3)	Bond Pad #8 (Vg1)

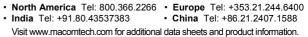
Bias Arrangement

5



Bypass Capacitors - See App Note [2]





PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

M/A-COM Technology Solutions Inc. and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice.



Rev. V1 Mimi× Broadband

Transmitter 32.0-45.0 GHz

Technology Solutions

Rev. V1 Mimi★ Broadband

MTTF Table (TBD)

These numbers were calculated based on accelerated life test information and thermal model analysis received from the fabricating foundry.

Backplate Temperature	Channel Temperature	Rth MTTF Hours		FITs
55 deg Celsius	deg Celsius	C/W	E+	Ē
75 deg Celsius	deg Celsius	C/W	Et	Б
95 deg Celsius	deg Celsius	C/W	E+	ц

Bias Conditions: Vd1=Vd2=4.0V, Id1=160 mA, Id2=145 mA

ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

M/A-COM Technology Solutions Inc. and its affiliates reserve the right to make

changes to the product(s) or information contained herein without notice.



Transmitter 32.0-45.0 GHz

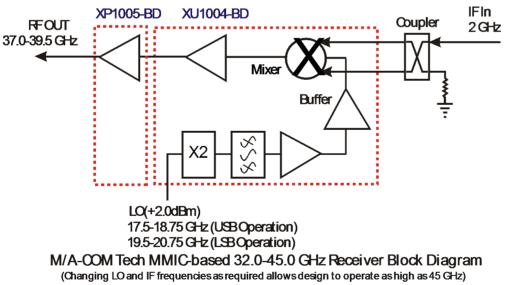
Rev. V1 Mimix Broadband

App Note [1] Biasing - As shown in the bonding diagram, this device is operated by separately biasing Vd1 and Vd2 with Vd(1,2)=4.0V, Id1=160mA and Id2=145mA. Additionally, a mixer and doubler bias are also required with Vg3=Vg4=-0.5V. Adjusting Vg3 and Vg4 above or below this value can adversely affect conversion gain, LO/RF isolation and intercept point performance. It is also recommended to use active biasing to keep the currents constant as the RF power and temperature vary; this gives the most reproducible results. Depending on the supply voltage available and the power dissipation constraints, the bias circuit may be a single transistor or a low power operational amplifier, with a low value resistor in series with the drain supply used to sense the current. The gate of the pHEMT is controlled to maintain correct drain current and thus drain voltage. The typical gate voltage needed to do this is -0.3V. Typically the gate is protected with Silicon diodes to limit the applied voltage. Also, make sure to sequence the applied voltage to ensure negative gate bias is available before applying the positive drain supply.

App Note [2] Bias Arrangement -

For Parallel Stage Bias (Recommended for general applications) - The same as Individual Stage Bias but all the drain or gate pad DC bypass capacitors (~100-200 pF) can be combined. Additional DC bypass capacitance (~0.01 uF) is also recommended to all DC or combination (if gate or drains are tied together) of DC bias pads.

For Individual Stage Bias - Each DC pad (Vd1,2 and Vg1,2,3,4) needs to have DC bypass capacitance (~100-200 pF) as close to the device as possible. Additional DC bypass capacitance (~0.01 uF) is also recommended.



Typical Application

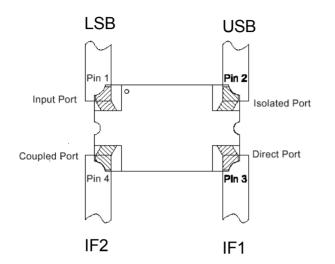
M/A-COM Tech's 32.0-45.0 GHz XU1004 GaAs MMIC Transmitter can be used in saturated radio applications and linear modulation schemes up to 128 QAM. The receiver can be used in upper and lower sideband applications from 32.0-45.0 GHz.

- ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. **PRELIMINARY**: Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.
- • North America Tel: 800.366.2266
 • Europe Tel: +353.21.244.6400

 • India Tel: +91.80.43537383
 • China Tel: +86.21.2407.1588
- Visit www.macomtech.com for additional data sheets and product information.

Transmitter 32.0-45.0 GHz

App Note [3] USB/LSB Selection -



An alternate method of Selection of USB or LSB:

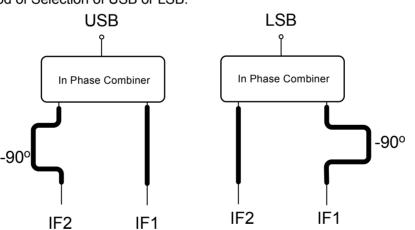


For Upper Side Band operation (USB):

With IF1 and IF2 connected to the direct port (0°) and coupled port (90°) respectively as shown in the diagram, the USB signal will reside on the isolated port. The input port must be loaded with 50 ohms.

For Lower Side Band operation (LSB):

With IF1 and IF2 connected to the direct port (0°) and coupled port (90°) respectively as shown in the diagram, the LSB signal will reside on the input port. The isolated port must be loaded with 50 ohms.



ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

- North America Tel: 800.366.2266
 Europe Tel: +353.21.244.6400
 India Tel: +91.80.43537383
 China Tel: +86.21.2407.1588
- Visit www.macomtech.com for additional data sheets and product information.

Transmitter 32.0-45.0 GHz

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these class 2 devices.

ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or protype measurements. Commitment to develop is not guaranteed. PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

9

Visit www.macomtech.com for additional data sheets and product information.

M/A-COM Technology Solutions Inc. and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice.



Rev. V1 Mimix Broadband

North America
 Tel:
 800.366.2266
 Europe
 Tel:
 +353.21.244.6400
 Ochina
 Tel:
 +86.21.2407.1588
 Ochina
 Ochina
 Tel:
 +86.21.2407.1588
 Ochina
 Ochina
 Tel:
 +86.21.2407.1588
 Ochina
 Ochina